

AMENDMENTS TO THE SPECIFICATION

Please replace the present title with the following amended title:

COMPOUND SEMICONDUCTOR LIGHT-EMITTING DEVICE-~~AND~~
~~PRODUCTION METHOD THEREOF~~ WITH AN AlGaInP LIGHT-EMITTING LAYER
FORMED WITHIN

**Please replace the paragraph on page 1 of the specification under the heading
“CROSS-REFERENCE TO RELATED APPLICATION” with the following amended
paragraph:**

~~Priority is claimed to Japanese application No. 2004-095145, filed March 29, 2004,~~
~~which are incorporated herein by reference. This application also claims the benefit pursuant to~~
~~35 U.S.C. § 119(e)(1) is a 371 of PCT/JP2005/006520 filed March 28, 2005, claiming benefit of~~
~~U.S. Provisional Applications, No. Application No. 60/559,429 filed April 6, 2004. Priority to~~
~~Japanese Application No. 2004-095145 filed March 29, 2004 is also claimed, incorporated~~
herein by reference.